



Silicon NPN Planar RF Transistor

Electrostatic sensitive device.
Observe precautions for handling.

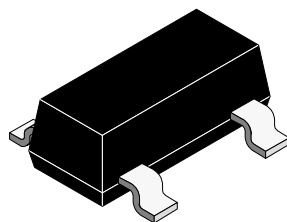
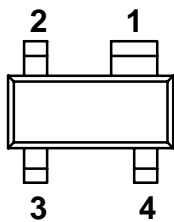


Applications

For low noise, low distortion broadband amplifiers in telecommunications and antenna systems and power amplifiers for DECT and PCN systems at collector currents between 20 mA and 80 mA up to 2 GHz

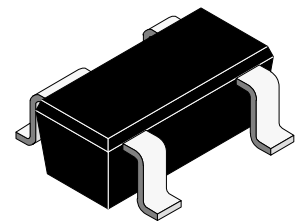
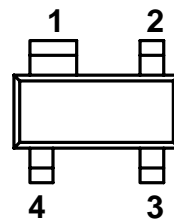
Features

- Low noise figure
- High transition frequency $f_T = 7.5$ GHz
- Excellent large signal behaviour



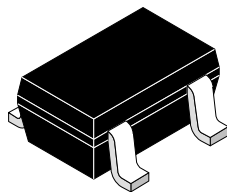
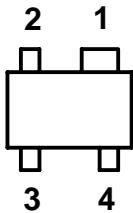
13628

BFP196T Marking: 196
Plastic case (SOT 143)
1 = Collector, 2 = Emitter, 3 = Base, 4 = Emitter



13629

BFP193TR Marking: R96
Plastic case (SOT 143R)
1 = Collector, 2 = Emitter, 3 = Base, 4 = Emitter



13632

BFP193TW Marking: W96
Plastic case (SOT 343)
1 = Collector, 2 = Emitter, 3 = Base, 4 = Emitter

Absolute Maximum Ratings

$T_{amb} = 25^\circ\text{C}$, unless otherwise specified

Parameter	Test Conditions	Type	Symbol	Value	Unit
Collector-base voltage			V_{CBO}	20	V
Collector-emitter voltage			V_{CEO}	12	V
Emitter-base voltage			V_{EBO}	2	V
Collector current			I_C	100	mA
Total power dissipation	$T_{amb} \leq 60^\circ\text{C}$		P_{tot}	500	mW
Junction temperature			T_j	150	$^\circ\text{C}$
Storage temperature range			T_{stg}	-65 to +150	$^\circ\text{C}$

Maximum Thermal Resistance

$T_{amb} = 25^{\circ}\text{C}$, unless otherwise specified

Parameter	Test Conditions	Symbol	Value	Unit
Junction ambient	on glass fibre printed board (25 x 20 x 1.5) mm ³ plated with 35μm Cu	R_{thJA}	180	K/W

Electrical DC Characteristics

$T_{amb} = 25^{\circ}\text{C}$, unless otherwise specified

Parameter	Test Conditions	Symbol	Min.	Typ.	Max.	Unit
Collector cut-off current	$V_{CE} = 20\text{ V}, V_{BE} = 0$	I_{CES}			100	μA
Collector-base cut-off current	$V_{CB} = 10\text{ V}, I_E = 0$	I_{CBO}			100	nA
Emitter-base cut-off current	$V_{EB} = 1\text{ V}, I_C = 0$	I_{EBO}			1	μA
Collector-emitter breakdown voltage	$I_C = 1\text{ mA}, I_B = 0$	$V_{(BR)CEO}$	12			V
Collector-emitter saturation voltage	$I_C = 70\text{ mA}, I_B = 7\text{ mA}$	V_{CEsat}		0.1	0.5	V
DC forward current transfer ratio	$V_{CE} = 8\text{ V}, I_C = 50\text{ mA}$	h_{FE}	50	100	150	

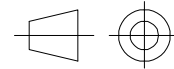
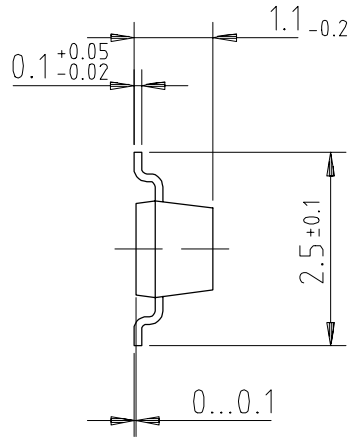
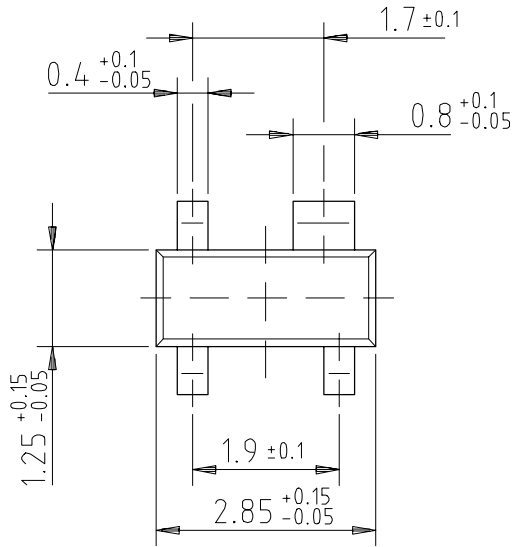
Electrical AC Characteristics

$T_{amb} = 25^{\circ}\text{C}$, unless otherwise specified

Parameter	Test Conditions	Symbol	Min.	Typ.	Max.	Unit
Transition frequency	$V_{CE} = 8\text{ V}, I_C = 50\text{ mA}, f = 1\text{ GHz}$	f_T	6	7.5		GHz
Collector-base capacitance	$V_{CB} = 10\text{ V}, f = 1\text{ MHz}$	C_{cb}		1.0	1.4	pF
Collector-emitter capacitance	$V_{CE} = 10\text{ V}, f = 1\text{ MHz}$	C_{ce}		0.3		pF
Emitter-base capacitance	$V_{EB} = 0.5\text{ V}, f = 1\text{ MHz}$	C_{eb}		3.5		pF
Noise figure	$V_{CE} = 8\text{ V}, I_C = 20\text{ mA}, Z_S = Z_{Sopt}, Z_L = 50\ \Omega, f = 900\text{ MHz}$	F		1.5		dB
	$V_{CE} = 8\text{ V}, I_C = 20\text{ mA}, Z_S = Z_{Sopt}, Z_L = 50\ \Omega, f = 2\text{ GHz}$	F		2.5		dB
Power gain	$V_{CE} = 8\text{ V}, I_C = 50\text{ mA}, Z_S = Z_{Sopt}, Z_L = 50\ \Omega, f = 900\text{ MHz}$	G_{pe}		16		dB
	$V_{CE} = 8\text{ V}, I_C = 50\text{ mA}, Z_S = Z_{Sopt}, Z_L = 50\ \Omega, f = 2\text{ GHz}$	G_{pe}		10		dB
Transducer gain	$V_{CE} = 8\text{ V}, I_C = 50\text{ mA}, Z_0 = 50\ \Omega, f = 900\text{ MHz}$	$ S_{21e} ^2$		12.5		dB
	$V_{CE} = 8\text{ V}, I_C = 50\text{ mA}, Z_0 = 50\ \Omega, f = 2\text{ GHz}$	$ S_{21e} ^2$		6.5		dB
Third order intercept point at output	$V_{CE} = 8\text{ V}, I_C = 50\text{ mA}, f = 900\text{ MHz}$	IP_3		36		dBm



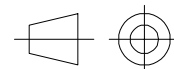
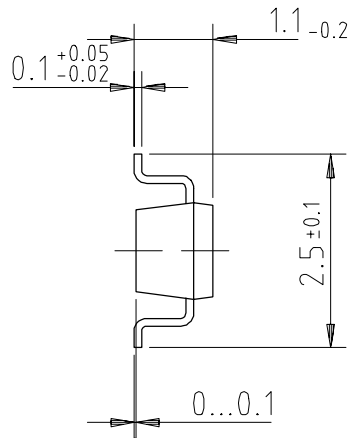
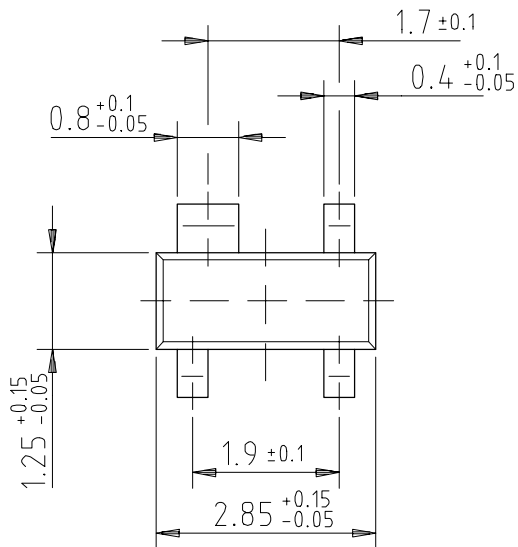
Dimensions of BFP196T in mm



96 12240

technical drawings
according to DIN
specifications

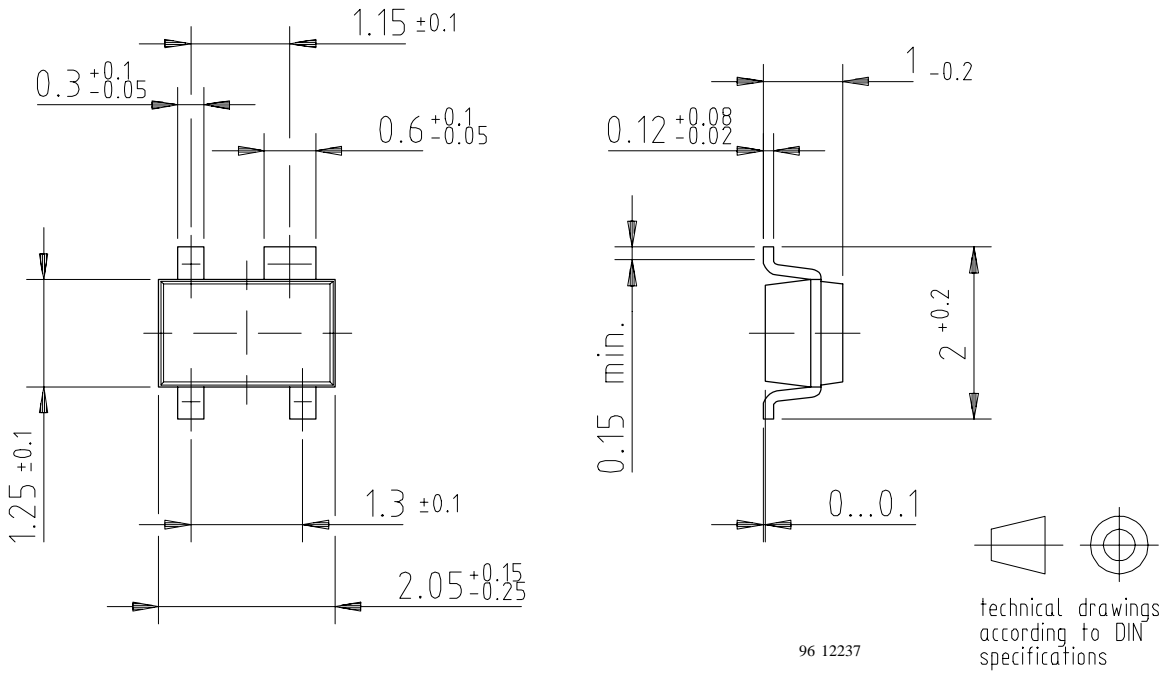
Dimensions of BFP196TR in mm



96 12239

technical drawings
according to DIN
specifications

Dimensions of BFP196TW in mm





Ozone Depleting Substances Policy Statement

It is the policy of **Vishay Semiconductor GmbH** to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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